

Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	-40	V
Gate-Source Voltage (No		(Note 6)	V _{GS}	±20	V
Single Pulsed Avalanche Energy (Note 12		(Note 12)	E _{AS}	50	mJ
Single Pulsed Avalanche Current (Note 12)		(Note 12)	I _{AS}	-20.3	A
		(Note 8)		-10.5	
Continuous Drain Current	V _{GS} = -10V	$T_A = +70^{\circ}C \text{ (Note 8)}$	lσ	-8.40	Α
		(Note 7)		-7.2	
Pulsed Drain Current	$V_{GS} = -10V$	(Note 9)	I _{DM}	-28.9	Α
Continuous Source Current (Body Diode) (Note 8)		I _S	-10.1	Α	
Pulsed Source Current (Body Diode) (Note 8)		I _{SM}	-28.9	А	

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 7)		4.18 33.4		
Power Dissipation Linear Derating Factor	(Note 8)	P _D	8.9 71.4	W mW/°C	
	(Note 10)		2.14 17.1		
	(Note 7)		29.9	2011	
Thermal Resistance, Junction to Ambient	(Note 8)	$R_{ hetaJA}$	14.0		
	(Note 10)	1	58.4	°C/W	
Thermal Resistance, Junction to Lead (Note 11)		$R_{ heta JL}$	2.46		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

Notes:

- 6. AEC-Q101 V_{GS} maximum is ±16V.
- 7. For a device surface mounted on 50mm x 50mm x 1.6mm FR-4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
- 8. Same as note 7, except the device is measured at $t \le 10s$.
- 9. Same as note 7, except the device is pulsed with D = 0.02 and pulse width 300µs. The pulse current is limited by the maximum junction temperature.

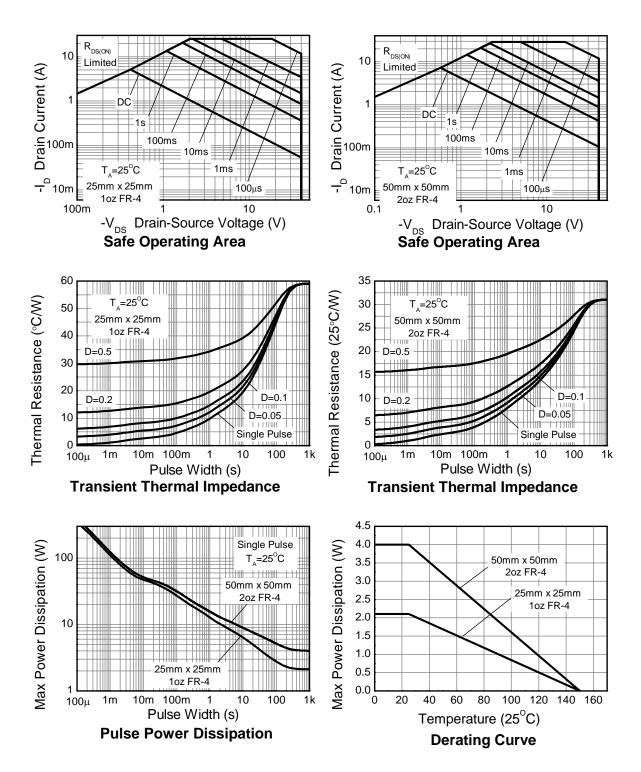
 10. For a device surface mounted on 25mm x 25mm x 1.6mm FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is
- measured when operating in a steady-state condition.

 11. Thermal resistance from junction to solder-point (at the end of the drain lead).

 12. UIS in production with L = 100μH, V_{DD} = -40V.



Thermal Characteristics





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

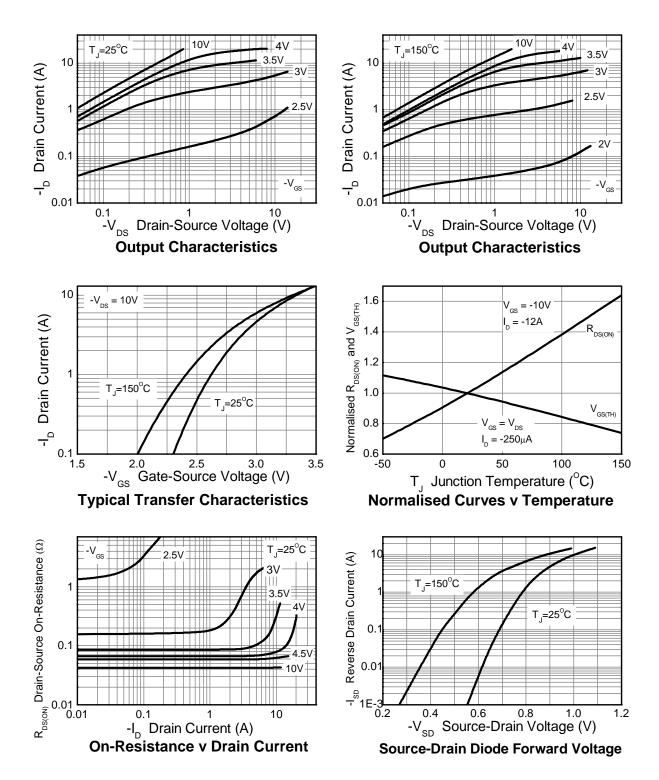
Characteristic	Symbol	Min	Тур	Max	Unit	Test Co	ondition
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV _{DSS}	-40	_	_	V	$I_D = -250 \mu A, V_{GS}$	= 0V
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-0.5	μΑ	$V_{DS} = -40V, V_{GS}$	= 0V
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS}$	= 0V
ON CHARACTERISTICS							
Gate Threshold Voltage	V _{GS(TH)}	-1.0	_	-3.0	V	$I_D = -250 \mu A, V_{DS}$	= V _{GS}
Static Drain-Source On-Resistance (Note 14)			0.041	0.051	Ω	$V_{GS} = -10V, I_{D} =$	-12A
Static Dialif-Source Off-Resistance (Note 14)	R _{DS(ON)}		0.059	0.085		$V_{GS} = -4.5V, I_{D} =$	-8A
Forward Transconductance (Notes 13 & 14)	g fs	_	16.6	_	S	V _{DS} = -15V, I _D = -12A	
Diode Forward Voltage (Note 13)	V_{SD}	_	-0.98	-1.2	V	$I_S = -12A, V_{GS} = 0V$	
Reverse Recovery Time (Note 14)	t _{rr}		138	_	ns	1 400 11/11 4000/ -	
Reverse Recovery Charge (Note 13)	Qrr	_	841	_	nC	$I_S = -12A$, di/dt =	100Α/μ\$
DYNAMIC CHARACTERISTICS (Note 14)							
Input Capacitance	CISS	_	674	_	pF	V _{DS} = -20V, V _{GS} = 0V -f = 1MHz	
Output Capacitance	Coss	_	115	_	рF		
Reverse Transfer Capacitance	C _{RSS}	_	67.7	_	pF		
Total Gate Charge (Note 15)	Q_{G}	_	7.0	_	nC	$V_{GS} = -4.5V$	
Total Gate Charge (Note 15)	Q_G	_	14	_	nC	$V_{DS} = -20V$ $I_{D} = -12A$	
Gate-Source Charge (Note 15)	Q _{GS}	_	2.2	_	nC		
Gate-Drain Charge (Note 15)	Q_{GD}	_	3.7	_	nC		
Turn-On Delay Time (Note 15)	t _{d(on)}	_	2.3	_	ns		
Turn-On Rise Time (Note 15)	t _r	_	14.1		ns	$V_{DD} = -20V, V_{GS}$	= -10V
Turn-Off Delay Time (Note 15)	t _{d(off)}	_	25.1	_	ns	$I_D = -12A, R_G \cong 6.0\Omega$	
Turn-Off Fall Time (Note 15)	t _f	_	14.3	_	ns		

Notes:

- 13. Measured under pulsed conditions. Pulse width $\leq 300\mu s$; duty cycle $\leq 2\%$. 14. For design aid only, not subject to production testing. 15. Switching characteristics are independent of operating junction temperatures.

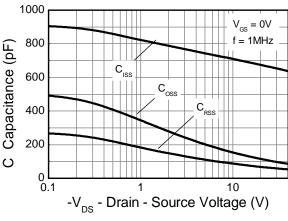


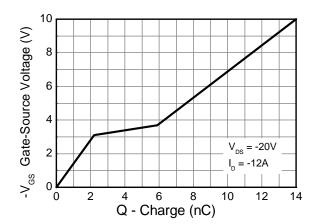
Typical Characteristics





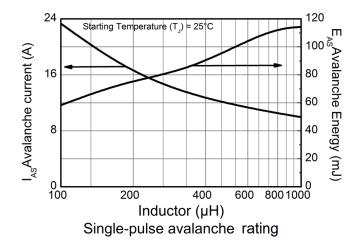
Typical Characteristics (Cont.)





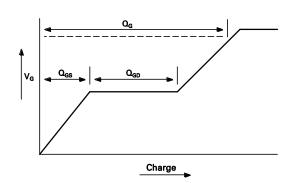
Capacitance v Drain-Source Voltage

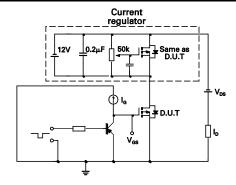
Gate-Source Voltage v Gate Charge





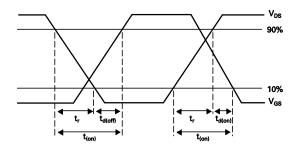
Test Circuits

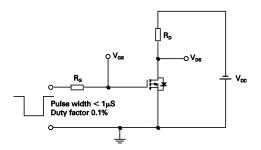




Basic gate charge waveform

Gate charge test circuit





Switching time waveforms

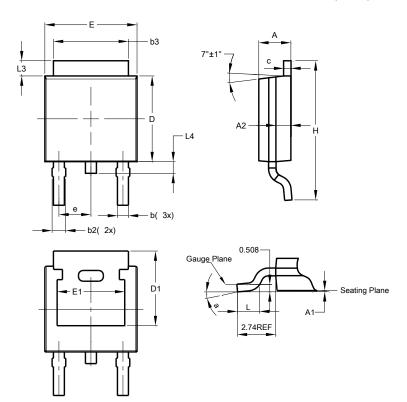
Switching time test circuit



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK)

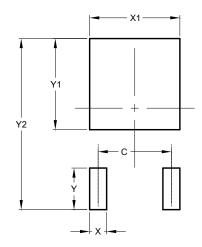


TO252 (DPAK)				
Dim	Min	Max	Тур	
Α	2.19	2.39	2.29	
A1	0.00	0.13	0.08	
A2	0.97	1.17	1.07	
b	0.64	0.88	0.783	
b2	0.76	1.14	0.95	
b3	5.21	5.46	5.33	
С	0.45	0.58	0.531	
D	6.00	6.20	6.10	
D1	5.21	-	-	
е	-	-	2.286	
Е	6.45	6.70	6.58	
E1	4.32	-	i	
Н	9.40	10.41	9.91	
L	1.40	1.78	1.59	
L3	0.88	1.27	1.08	
L4	0.64	1.02	0.83	
а	0°	10°	-	
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK)



Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Υ	2.600
Y1	5.700
Y2	10.700



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